

Inductance of $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ Thin-Films With and Without Superconducting Ground Planes

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Abstract—We experimentally measured and compared the sheet inductance of $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ (YBCO) films with and without superconducting ground planes. Specifically, we fabricated several superconducting quantum interference devices from single and multilayer films with different geometries using a focused helium ion beam. Measurements of the device electrical transport properties were analyzed to determine the sheet inductance. Additionally, temperature dependent measurements of the inductance were used in order to separate the contributions from geometric and kinetic inductance. We found that the presence of a ground plane in our multilayer structure significantly reduces the contribution of the geometric inductance with no detectable change in the kinetic inductance.

Index Terms—Geometric inductance, ground plane, kinetic inductance, multilayer, $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ (YBCO).

I. INTRODUCTION

SUPERCONDUCTING computing provides a promising high performance, energy-efficient alternative to conventional computing, where power and cooling for large-scale computing systems are drastically becoming unmanageable problems—especially for centralized supercomputers and data centers. With the advantages of wide temperature operation and low cost of cooling, high critical temperature (T_C) superconductors could revolutionize future systems. The computing speed and energy cost per bit of superconducting circuits depend strongly on their inductance. Therefore, critical factors affecting the performance of superconducting devices include precise design and control of the inductance. Additionally, technological improvements in the growth patterning and the interconnection of multiple layers can further optimize the inductance of more complex digital circuits [1]–[3].

Recent innovations in high-quality and reproducible $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ (YBCO) devices fabricated by focused helium

ion beam focused helium ion beam (FHIB) irradiation[4]–[8] could aid in the development of high- T_C superconducting digital circuits. the beam energy of the FHIB is not high enough to penetrate thick films, unlike the prior-art of masked ion beam irradiated junctions [9]. Therefore, FHIB junctions are only suitable in the films with thicknesses much less than the penetration depth $\lambda_0 \sim 150$ nm [10]. This is particularly important because the inductance is dependant on the two-dimensional penetration depth, which rapidly increases with decreasing film thickness t , $\lambda_{\perp} = \lambda_L^2/t$.

In previous work [11]–[14], the total sheet inductance of YBCO can be reduced to just ~ 1 pH/ \square with the addition of a ground plane. These demonstrations utilize 300 to 400 nm thick dielectric layers and 200 to 300 nm thick counter electrodes. In these structures, the film thicknesses are larger than their penetration depths. However, for films that are thinner than the material's penetration depth, the kinetic inductance dominates, meriting the study of the novel inductive properties of these materials. Therefore, in this article, we experimentally measured the geometric and kinetic inductance of commercially grown single and double layer YBCO thin films grown by reactive coevaporation [15] onto sapphire wafers with thicknesses much less than their penetration depth.

II. EXPERIMENT

Single and multilayer films of YBCO were grown on r -plane sapphire buffered with 20 nm of CeO_2 by Ceraco GmbH, with thicknesses much less than the penetration depth of YBCO. The single-layer film was 35-nm-thick. The multilayer structure consisted of two superconducting layers separated by an insulator with the following thicknesses: 35 nm YBCO, 75 nm CeO_2 , and 135 nm YBCO (from top to bottom). The insulating layer should be thick enough to prevent the leakage current from flowing through the pinholes in the CeO_2 . The total thickness needs to be kept to under 300 nm in order to ensure the film stability and to prevent cracking from happening during the deposition process. A 200-nm-thick gold electrode was evaporated *in situ* to make electrical contacts. In previous work, we detailed the synthesis of these multilayer films and verified that the two superconducting layers were isolated from one another with no pin-hole shorts through the CeO_2 insulator [16].

To investigate the sheet inductance (inductance per square), we utilized superconducting quantum interference devices (SQUIDs) with electrodes for direct current injection into the SQUID loop [17]. In these devices, inductance can be accurately

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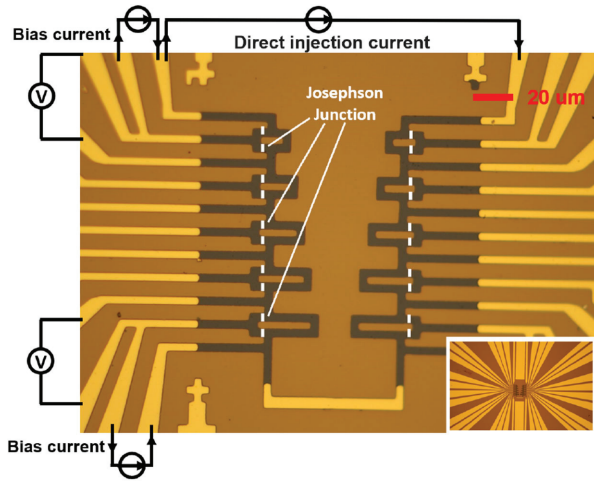


Fig. 1. Optical photograph of YBCO SQUIDs fabricated from the multilayer film. The center dark area is the exposed top YBCO pattern, where the gold electrode layer was chemically etched away. The solid white lines represent the Josephson junctions, which are directly written on the exposed top YBCO layer by the helium ion irradiation. The design is a symmetrical pattern, mirrored on either side of the center. From the top to the bottom, the direct control line follows the five SQUID loops that have 5, 7, 9, 11 and 13 squares of inductance.

determined by measuring the SQUIDs' magnetic field response to the injection current [18]. We fabricated several direct-inject SQUIDs in the upper layer of the multilayer sample as well as in a second single-layer sample using a fabrication method detailed in previous work [19], [20]. The multilayer SQUID chip is shown in Fig. 1. The area of the SQUID loop can be defined as the area of the largest single geometric square that can fit inside of the loop, times the number of those squares that make up the loop when the square is used to tile the geometric area. In our design, the SQUIDs have different areas of the loops with different numbers of squares: 5, 7, 9, 11, and 13, to accurately determine the sheet inductance of the material. The chips were created using laser lithography and argon ion milling in order to pattern the large-scale electrodes into both the gold and the top YBCO layer. In this situation, there is no return current flowing through the ground plane (the bottom YBCO layer). Therefore, the undesirable influence of the magnetic fields induced by the bias and the ground return currents can be neglected. Subsequently, Josephson junctions were written using a Zeiss Orion Plus helium ion microscope applying dosages of about 8×10^{16} He^+/cm^2 to modify portions of the superconducting film into insulating lines that form Josephson junctions [4].

Completed devices were mounted in an evacuated dip probe and cooled in a liquid helium Dewar with magnetic shielding for electrical measurements. Each device was individually tested by dc biasing above the critical current (297.8 and 122.8 μA , respectively, for the single layer and multilayer SQUID at 4.2 K) and measuring the voltage-magnetic field (V - B) characteristics with an external magnetic field applied normal to the substrate from the backside of the sample. Fig. 2(a) shows the V - B plot for the single-layer device with a large modulation voltage amplitude of 135 μV . In contrast, Fig. 2(b) shows the multilayer device with no detectable modulation. This demonstrates that

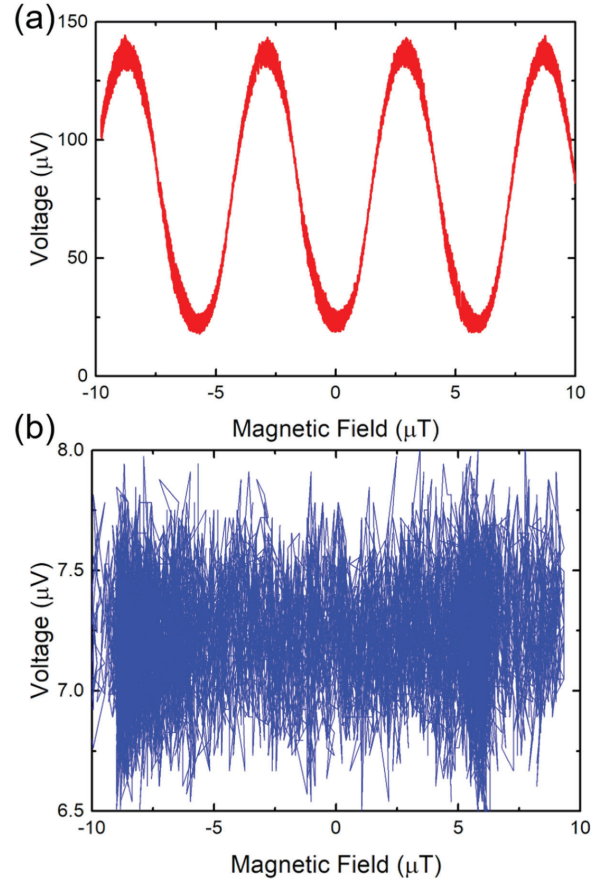


Fig. 2. Voltage external magnetic field characteristics for (a) single-layer thin film SQUID with 135 μV modulation amplitude and (b) SQUID on multilayer film with ground plane with no voltage-external magnetic field response.

the ground plane is superconducting and that it is sufficiently shielding the SQUIDs from the applied field.

Next, we measured the voltage response of the SQUID by injecting a current through the common injection line. The voltage modulation of the SQUIDs as a function of injection current (V - I_L) are shown in Fig. 3(a) and (b) for the single layer and for the multilayer, respectively. Both chips were operated over a large temperature range from 4 to 60 K. At 4.2 K, the modulation amplitudes were 60 μV for the single layer and 110 μV for the multilayer SQUID chip.

By comparing the magnetic field periods from the external field ΔB to the periodicity in current from the injection line I_L , we can accurately determine the injection inductance L_I and the sheet inductance $L_S = L_I/N$, where N is the number of squares of material. The inductance value of the SQUID loop is determined from $L = \Phi_0/\Delta B$. Using a linear fit shown in Fig. 4, the sheet inductance is obtained from the inductance plotted against the lengths of the square loops. At the lowest temperatures, we found L_S to be 6.2 ± 0.2 pH/\square and 4.3 ± 0.4 pH/\square for the single and multilayer films, respectively. This demonstrates that the ground plane in the multilayer device reduces the sheet inductance by almost a factor of two.

The thickness of the patterned YBCO layer (35 nm) is thin compared to the penetration depth of a magnetic field into

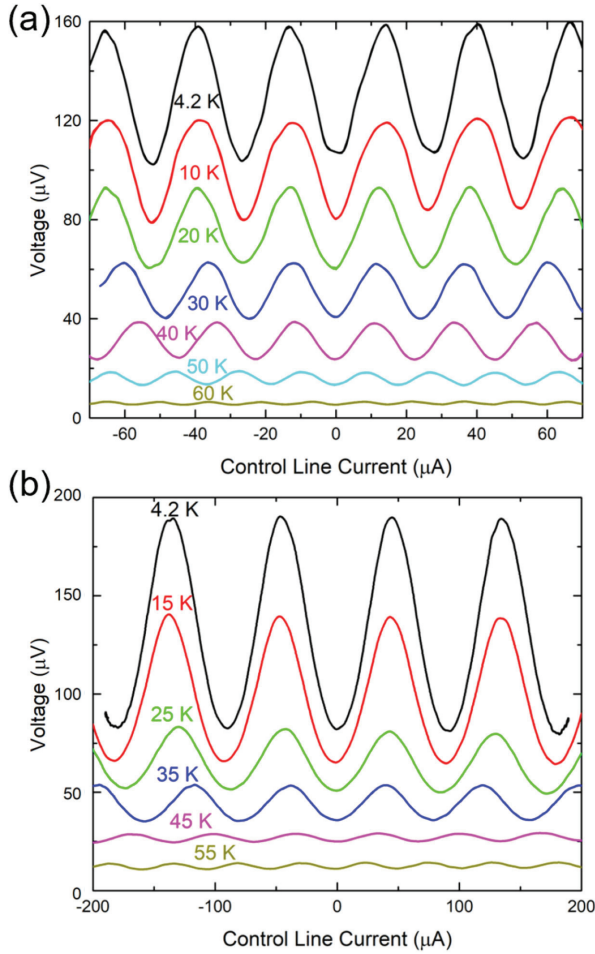


Fig. 3. Representative (a) single layer and (b) multilayer SQUID voltage— injection current characteristics ($V-I_L$) for several temperatures. The voltage modulation curves are all offsetting by $\sim 10 \mu\text{V}$ for clarity.

the superconductor. Because the film is sufficiently thin, the total inductance can be limited to only contributions from the kinetic and geometric inductance. To differentiate between the contributions from the geometric and kinetic inductance, we measured the dependence of the sheet inductance on temperature (see Fig. 5). The data are fitted using a model of d -wave superconductors with impurity scattering [21]–[23]

$$L_s = L_g + L_k(0)/[1 - (T/T_C)^2] \quad (1)$$

where L_g is the geometric inductance, L_k is the dependence of kinetic inductance on temperature, $L_k(0)$ is the value at 0 K, and T_C is the YBCO transition temperature. From a resistivity versus temperature measurement, we found the T_C taken at zero resistance for the single layer YBCO film, as well as for the top YBCO layer in the multilayer structure. The T_C values were found to be 79 K and 82 K, respectively.

Fig. 5 shows the dependence of inductance L_s on temperature was plotted against $[1 - (T/T_C)^2]^{-1}$, linearly fitted to (1). From the fit, we found the inductance properties of the single and multilayer devices. The geometric inductances L_g are $2.0 \pm 0.2 \text{ pH}/\square$ and $0.1 \pm 0.4 \text{ pH}/\square$, respectively, while the 0 K kinetic inductance L_k are $4.1 \pm 0.2 \text{ pH}/\square$ and 4.3

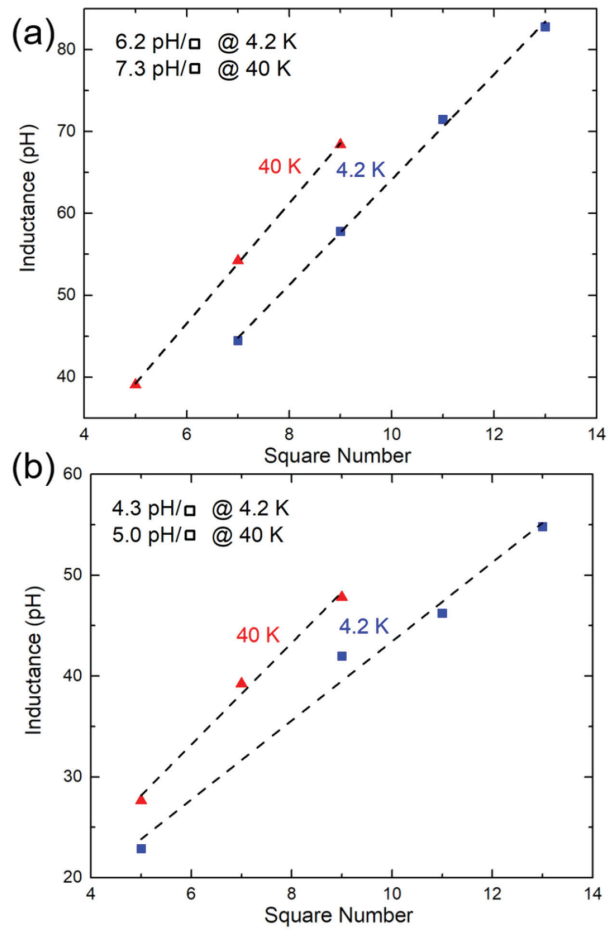


Fig. 4. Relationship of the number of squares in a SQUID loop versus the total inductance of that loop for (a) single and (b) multilayer films at high and low temperatures. The slope of the trend line gives the sheet inductance.

$\pm 0.4 \text{ pH}/\square$. As shown in Fig. 5, the geometric inductance of the multilayer is much smaller than that of the single-layer device, indicating that the ground plane can significantly reduce the contribution of the geometric inductance and effectively reduce the total sheet inductance with no detectable change in the kinetic inductance. As the geometric inductance refers to the magnetic energy stored within the film, the shielding affect from the ground plane is indicated by elimination of the geometric inductance. Moreover, the reduction of geometric inductance allows for higher operation frequencies in resultant devices.

The magnitude of the temperature dependent kinetic inductance is determined by the film thickness and is proportional to the the penetration depth [24], $L_k/\square = \mu_0 \lambda(T)^2/t$, where $\lambda(T) = \lambda(0)/\sqrt{1 - (T/T_C)^2}$. The kinetic inductance becomes constant when there is no change in the penetration depth at low temperatures. For the inductance of the multilayer device, the kinetic inductance dominates, which leads to the inductance becoming constant at low temperatures. It is also responsible for the appearance of an upturn in the plot of Fig. 5(b) at low temperatures. From the kinetic inductance, the penetration depth can be estimated to be about 290 nm. However, the calculated penetration depth may be larger than the actual value due to uncertainties in the film thickness measurement.

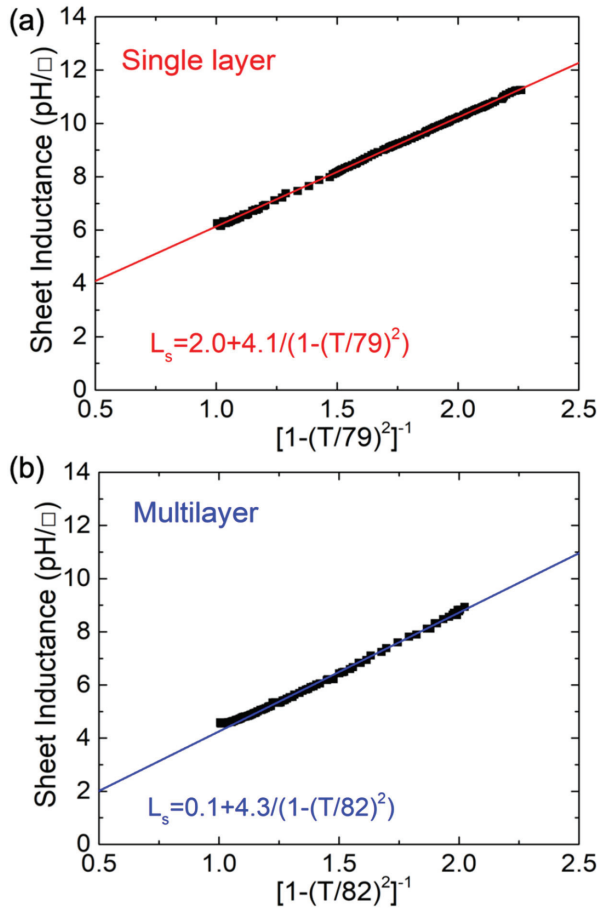


Fig. 5. Relationship between inductance L_s and $[1 - (T/T_c)^2]^{-1}$. Black squares are the measurement data. The solid curve is the result of the fit.

The kinetic inductance responds to the superconducting state and the nondissipative kinetic energy of the supercurrent [25]. The addition of a ground plane does not induce more energy dissipation to the device and eliminates the magnetic energy stored within the film.

III. CONCLUSION

In this article, we investigated the inductance properties of YBCO single and multilayer films grown commercially on large area wafers with thickness less than the penetration depth. The presence of a superconducting ground plane in the multilayer film substantially reduces the geometric component of the sheet inductance. This significantly relaxes circuit design constraints for single flux quanta device components requiring small inductance such as adiabatic quantum flux paramtrons [26]. Furthermore, we showed that the ground plane can serve as an environmental magnetic shielding layer for SQUID devices. This could aid SQUID [27], [28] or Josephson array [29] based applications for magnetically noisy environments.

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